PCN Number: 202		220127001.1		PCN	PCN Date:		January 31, 2022		
Title:Qualification of new Datasheet update									hnology, Die Revision, select devices
Customer	Contact:		PCI	<u>N Manager</u>		Dept:			Quality Services
Proposed 1 st Ship Date:				Estimat Availabi	ted Sample ility:		9	Date provided at sample request.	
Change Type:									
Assen	nbly Site			Assembly Proc	ess		\boxtimes	Assembly Materials	
Desig	n		\boxtimes	Electrical Specification				Mechanical Specification	
Test S	Site		Packing/Shipping/Labeling		ng		Test Process		
Wafer Bump Site			Wafer Bump Material				Wafer Bump Process		
Wafer Fab Site		\boxtimes	Wafer Fab Materials			\boxtimes	Wafer Fab Process		
			Part number change						
					ataila				

PCN Details

Description of Change:

Texas Instruments is pleased to announce the qualification of a new fab & process technology (FFAB, BICOM3) and assembly site/BOM options (MLA) for selected devices as listed below in the product affected section.

C	urrent Fab Site	9	Additional Fab Site			
Current Fab Process Wafer Site Diameter		Additional Fab Site	Process	Wafer Diameter		
SFAB	JIBB	150 mm	FFAB	BICOM3	200 mm	

The die was also changed as a result of the process change.

Construction differences are noted below: Group 1 Devices:

	ASESH	TI Malaysia		
Die thickness (um)	203	191		
Mount compound	EY1000063	4147858		
Mold compound	EN2000631	4226323		
Wire type	Au	Cu		
Leadframe finish	NiPdAuAg	NiPdAu		
Marking Differences	A26 YMLL YM = YEAR MONTH DATE CODE LL = ASSEMBLY LOT CODE O = PIN 1 INDICATOR (MARK)	BB YM A26 O (CAV) BB = BB LETTERS YM = YEAR MONTH DATE CODE O = PIN 1 INDICATOR (DIMPLE) CAV = CAVITY NUMBER		

Group 2 Devices:

	Current - MLA	New - MLA
Mold Compound	4209640	4226323
Mount Compound	4205846	4147858
Bond Wire Composition/Diameter	Au/1.15 mils	Cu/1.0 mil
MSL	MSL3	MSL2

The datasheet will be changing as a result of the above mentioned changes. The datasheet change details can be reviewed in the datasheet revision history. The link to the revised datasheet is available in the table below.

	TEXAS INSTRUMENTS SB0S062C - SEPTEMBER 2000 - REVISED JANUARY 20	
С	nanges from Revision B (December 2015) to Revision C (December 2021) Page	9
•	Updated the numbering format for tables, figures, and cross-references throughout the document1	1
•	Added dual supply specification to Absolute Maximum Ratings	5
•	Deleted redundant operating temperature and input common mode voltage specifications in Recommended	
	Operating Conditions	5
•	Added dual supply and specified temperature specifications in Recommended Operating Conditions	5
•	Added proper signs for PSRR and input bias current specifications in <i>Electrical Characteristics</i>	7
•	Deleted V _O = 0 V test condition of common-mode voltage specification in <i>Electrical Characteristics</i>	7
•	Changed common-mode voltage specification from ±11.25 V minimum, to –11.25 V minimum and 11.25 V	
	maximum, in Electrical Characteristics	7
•	Changed minimum CMRR specification for INA126U/E, INA2126E from 83 dB to 80 dB in <i>Electrical</i>	
	Characteristics	7
•	Added typical input bias current specification of ±10 nA for INA126PA/UA/EA and INA2126PA/UA/EA in	
	Electrical Characteristics	7
•	Changed current noise specifications in <i>Electrical Characteristics</i> from 60 fA/ \sqrt{Hz} to 160 fA/ \sqrt{Hz} for f = 1 kHz, and from 2 pApp to 7.3 pApp for f = 0.1 Hz to 10 Hz	7
•	Changed test condition for short-circuit current specification in <i>Electrical Characteristics</i> from "Short circuit to ground" to "Continuous to $V_S / 2$ " for clarity	7
•	Changed short-circuit current specification in Electrical Characteristics from +10/-5 mA to ±5 mA	7
•	Deleted redundant voltage range, operating temperature range, and specification temperature range	
	specifications from Electrical Characteristics	7
•	Changed Figures 6-7, 6-10, 6-13, 6-14, 6-15, 6-16, 6-17	
•	Added Figure 6-11	9
_	• •	-

Product Family	Current Datasheet Number	New Datasheet Number	Link to full datasheet
INA126, INA2126	SBOS062B	SBOS062C	http://www.ti.com/product/INA126

Qual details are provided in the Qual Data Section.

Reason for Change:

These changes are part of our multiyear plan to transition products from our 150-milimeter factories to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

- -

Impact on Environmental Ratings

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS	REACH	Green Status	IEC 62474
🛛 No Change	🛛 No Change	🛛 No Change	🛛 No Change

Changes to product identification resulting from this PCN:

Fab Site Information:

Chip Site	Chip Site Chip Site Origin Code (20L)		Chip Site City	
SH-BIP-1	SHE	USA	Sherman	
FR-BIP-1	TID	DEU	Freising	

Die Rev:

Current	New		
Die Rev [2P]	Die Rev [2P]		
D	Α		

Assembly Site Information:

ASESH	ASH	CHN	Shanghai	
TI Malaysia	MLA	MYS	Kuala Lumpur	
Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (23L)	Assembly City	

Sample product shipping label (not actual product label)

TEXAS INSTRUMENTS MADE IN: Malaysia 20: MSL 2 /2600C/1 YEAR SEAL DT MSL 1 /235C/UNLIM 03/29/04 OPT: ITEM: S9 LBL: 5A (L)T0:1750 (1P) SN74LS07NSR (Q) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY (1T) 7523483SI2 (P) (2P) REV: (V) 0033317 (20L) GS0: SHE (2)L) GS0: SHE (2)L) AS0: MLA (2)L) ACO: MYS							
Product Affected:							
Group 1 - FFAB/Pr	ocess migration, Die R	ev, Datasheet & MLA	A/T Site + BOM updates:				
INA126E/250	INA126E/2K5	INA126EA/250	INA126EA/2K5G4				
INA126E/250G4	INA126E/2K5G4	INA126EA/2K5					
	·						
Group 2 - FFAB/Process migration, Die Rev, Datasheet and BOM updates:							
INA126U	INA126U/2K5G4	INA126UA/2K5	INA126UAG4				
INA126U/2K5	INA126UA						
	I						

Qualification Report

Approve Date 30-Nov-2021

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: <u>INA126U</u>	QBS Process Reference: INA828ID	QBS Process Reference: <u>OPA202ID</u>	QBS Package Reference: <u>INA849D</u>
HTOL	Life Test, 100C ^A	300 Hours	-	-	-	1/77/0
HTOL	Life Test, 150C	300 Hours	1/77/0	3/231/0	3/231/0	-
HBM	ESD - HBM	500 V	1/3/0	1/3/0	3/9/0	1/3/0
HBM	ESD - HBM	1000 V	1/3/0	1/3/0	3/9/0	1/3/0
HBM	ESD - HBM	2000 V	1/3/0	1/3/0	3/9/0	1/3/0
CDM	ESD - CDM	1000 V	1/3/0	1/3/0	3/9/0	1/3/0
CDM	ESD - CDM	1500 V	1/3/0	-	-	1/3/0
CDM	ESD - CDM	750 V	1/3/0	-	3/9/0	1/3/0
LU	Latch-up	Per JESD78	1/6/0	1/6/0	1/6/0	1/6/0
ED	Electrical Characterization	Per Datasheet Parameters	1/30/0	3/90/0	3/Pass	1/30/0
HAST	Biased HAST, 130C/85%RH	96 Hours	-	3/231/0	3/231/0	-
HTSL	High Temp Storage Bake 170C	420 Hours	-	3/231/0	3/231/0	3/231/0
LU	Latch-up	Per JESD78	1/6/0	1/6/0	1/6/0	1/6/0
TC	Temperature Cycle, -65/150C	500 Cycles	1/77/0	3/231/0	3/231/0	3/231/0
тнв	Biased Temperature and Humidity, 85C/85%RH	1000 Hours	-	-	-	3/231/0
UHAST	Unbiased HAST 130C/85%RH	96 Hours	-	3/231/0	3/231/0	3/231/0

- QBS: Qual By Similarity

- Qual Device INA126U is gualified at L2, 260C

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/tk Hours, and 170C/420 Hours
The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/tk Hours, and 170C/420 Hours
The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles
Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status: Qualified Pb-Free (SMT) and Green

^A Tj of device at 150C

Qualification Report

Approve Date 13-Jan-2022

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: <u>INA126E</u>	QBS Product Reference: <u>INA126U</u>	QBS Process Reference: <u>INA828ID</u>	QBS Package Reference: <u>OPA2145IDGK</u>	QBS Package Reference: <u>OPA2205ADGK</u>	QBS Package Reference: <u>OPA2206ADGK</u>
HTOL	Life Test, 150C	300 Hours	-	1/77/0	3/231/0	-	1/77/0	2/154/0
ELFR	Early Life Failure Rate, 150C	24 Hours	-	-	-	-	1/800/0	2/2400/0
HBM	ESD - HBM	2000V	-	1/3/0	1/3/0	-	1/3/0	1/3/0
CDM	ESD - CDM	1000V	1/3/0	1/3/0	1/3/0	1/3/0	1/3/0	2/6/0
LU	Latch-up	Per JESD78	-	1/6/0	1/6/0	-	1/6/0	1/6/0
ED	Electrical Characterization	Per Datasheet Parameters	1/30/0	1/30/0	3/90/0	1/30/0	1/30/0	1/30/0
HAST	Biased HAST, 130C/85%RH	96 Hours	-	-	3/231/0	-	1/77/0	2/154/0
HTSL	High Temp Storage Bake 170C	420 Hours	-	-	3/231/0	-	1/77/0	2/154/0
LI	Lead Pull	Lead Pull	-	-	-	-	1/6/0	2/12/0
TC	Temperature Cycle, - 65/150C	500 Cycles	-	1/77/0	3/231/0	1/77/0	1/77/0	2/154/0
UHAST	Unbiased HAST 130C/85%RH	96 Hours	-	-	3/231/0	1/77/0	1/77/0	2/154/0
- QBS: Qua	al <u>By</u> Similarity							

- Qual Device INA126E is gualified at L2, 260C

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles
Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free (SMT) and Green

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